

TrenchP™ **Power MOSFET**

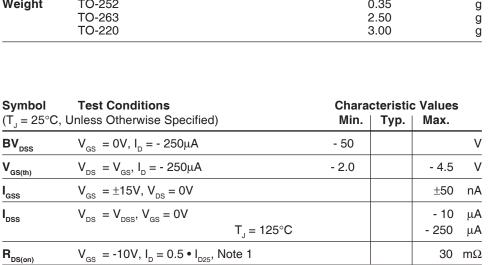
IXTY48P05T IXTA48P05T IXTP48P05T

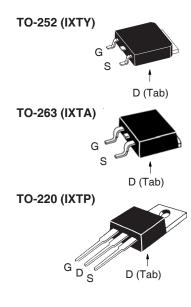
- 50V - 48A R_{DS(on)} $30 \text{m}\Omega$

P-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	T _J = 25°C to 150°C	- 50	V	
V _{DGR}	$T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}, R_{GS} = 1\text{M}\Omega$	- 50	V	
V _{GSS}	Continuous	<u>+</u> 15	V	
V _{GSM}	Transient	<u>+</u> 25	V	
I _{D25}	T _C = 25°C	- 48	A	
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	-150	Α	
I _A	T _C = 25°C	- 48	A	
E _{AS}	$T_{c} = 25^{\circ}C$	300	mJ	
P_{D}	T _C = 25°C	150	W	
T _J		-55 +150	°C	
T _{JM}		150	°C	
T _{stg}		-55 +150	°C	
T _L	Maximum Lead Temperature for Soldering	300	°C	
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C	
M _d	Mounting Torque (TO-220)	1.13 / 10	Nm/lb.in	
Weight	TO-252	0.35	g	
	TO-263	2.50	g	
	TO-220	3.00	g	





G = Gate= Drain S = SourceTab = Drain

Features

- International Standard Packages
- Avalanche Rated
- Extended FBSOA
- Fast Intrinsic Diode
- Low R_{DS(ON)} and Q_G

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- High-Side Switching
- Push Pull Amplifiers
- DC Choppers

30 $m\Omega$

- Automatic Test Equipment
- Current Regulators
- Battery Charger Applications

 $\boldsymbol{R}_{DS(\underline{on})}$



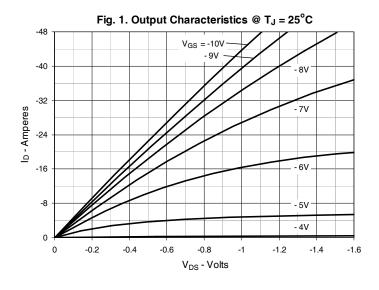
•				haracteristic Values		
$(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		Тур.	Max.			
\mathbf{g}_{fs}		$V_{DS} = -10V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$	16	26	S	
C _{iss}	}	$V_{GS} = 0V, V_{DS} = -25V, f = 1MHz$		3660	pF	
\mathbf{C}_{oss}				495	pF	
\mathbf{C}_{rss}				215	pF	
t _{d(on)})	Resistive Switching Times $V_{_{GS}} = -10V, \ V_{_{DS}} = -30V, \ I_{_{D}} = 0.5 \bullet I_{_{D25}}$ $R_{_{G}} = 3\Omega \ (External)$		20	ns	
t _r				15	ns	
$\mathbf{t}_{d(off)}$	}			30	ns	
t _f	J			13	ns	
$\mathbf{Q}_{g(on)}$)			53	nC	
\mathbf{Q}_{gs}	}	$V_{GS} = -10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		16	nC	
\mathbf{Q}_{gd}				21	nC	
R _{thJC}					0.83 °C/W	
\mathbf{R}_{thCS}		TO-220		0.50	°C/W	

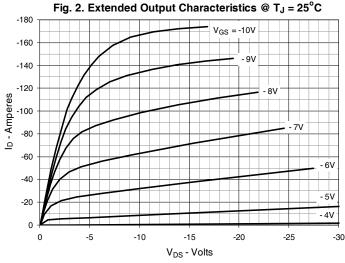
Source-Drain Diode

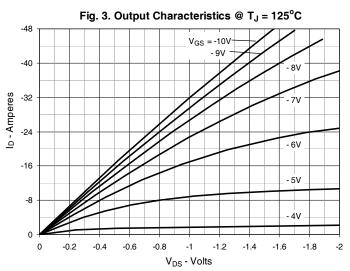
Symbol Test Conditions (T _J = 25°C, Unless Otherwise Specified)		Charac Min.	Characteristic Values Min.			
I _s	$V_{GS} = 0V$			- 48	A	
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			-192	Α	
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			-1.5	V	
$\left\{ egin{array}{ll} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array} ight\}$	$I_F = 0.5 \bullet I_{D25}$, -di/dt = -100A/ μ s $V_R = -25V$, $V_{GS} = 0V$		30 43.4 - 2.8		ns nC A	

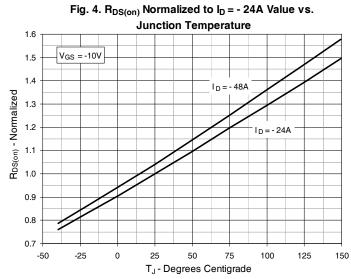
Note 1: Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

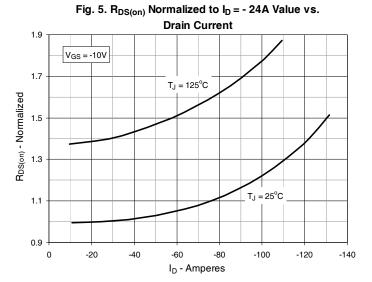


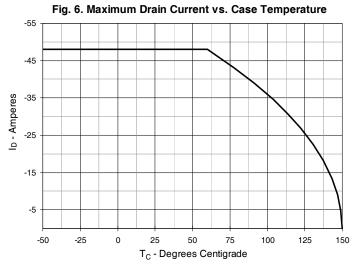




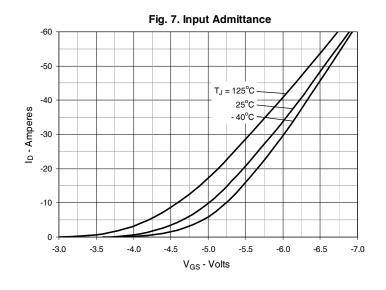


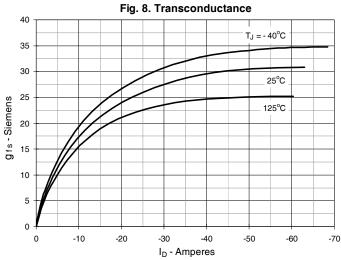


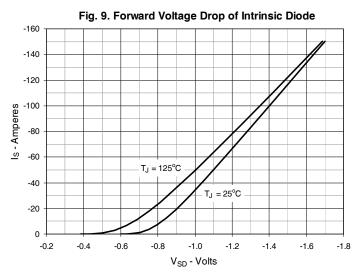


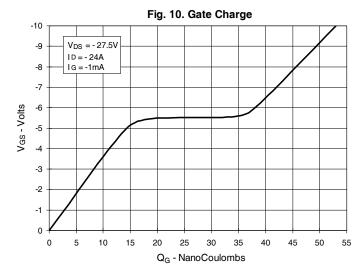


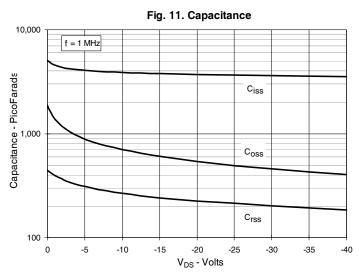


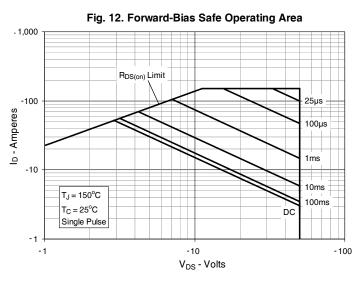










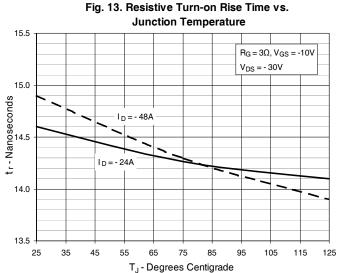


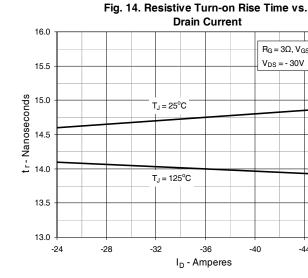
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

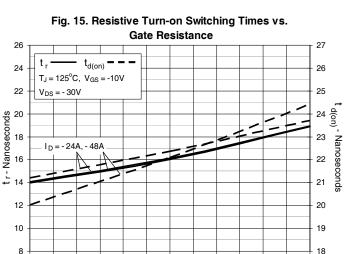
 $R_G = 3\Omega$, $V_{GS} = -10V$ $V_{DS} = -30V$

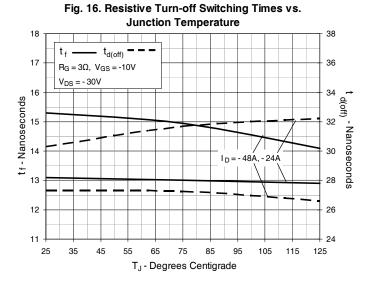
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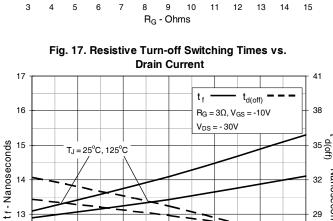










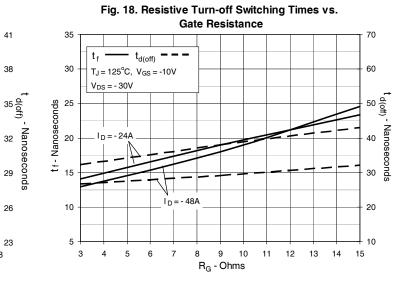


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I_D - Amperes

26

23

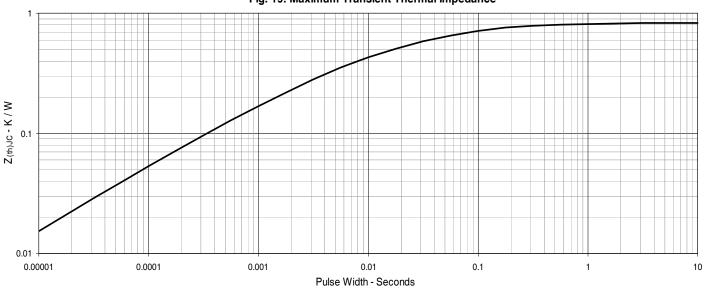


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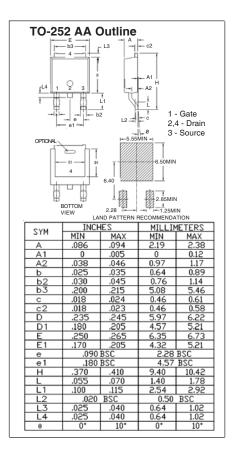
11

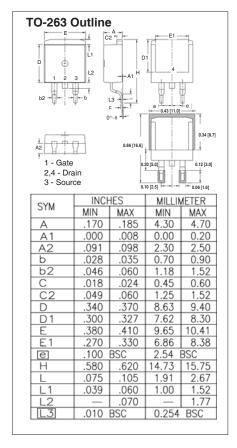
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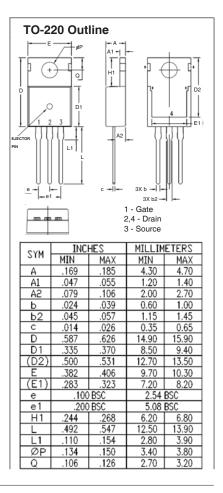
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